

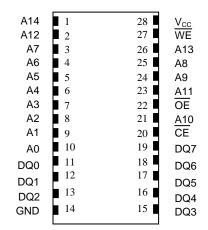
DS1230Y/AB 256k Nonvolatile SRAM

www.maxim-ic.com

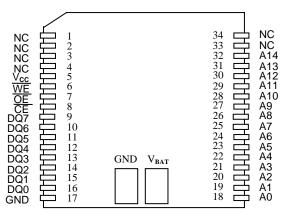
FEATURES

- 10 years minimum data retention in the absence of external power
- Data is automatically protected during power loss
- Replaces 32k x 8 volatile static RAM, EEPROM or Flash memory
- Unlimited write cycles
- Low-power CMOS
- Read and write access times as fast as 70 ns
- Lithium energy source is electrically disconnected to retain freshness until power is applied for the first time
- Full ±10% V_{CC} operating range (DS1230Y)
- Optional ±5% V_{CC} operating range (DS1230AB)
- Optional industrial temperature range of -40°C to +85°C, designated IND
- JEDEC standard 28-pin DIP package
- PowerCap Module (PCM) package
 - Directly surface-mountable module
 - Replaceable snap-on PowerCap provides lithium backup battery
 - Standardized pinout for all nonvolatile SRAM products
 - Detachment feature on PowerCap allows easy removal using a regular screwdriver

PIN ASSIGNMENT



28-Pin ENCAPSULATED PACKAGE 740-mil EXTENDED



34-Pin POWERCAP MODULE (PCM) (USES DS9034PC POWERCAP)

PIN DESCRIPTION

A0 - A14	Addrage Inputs
AU - A14	 Address Inputs
DQ0 - DQ7	- Data In/Data Out
CE	- Chip Enable
$\overline{ ext{WE}}$	- Write Enable
ŌĒ	- Output Enable
V_{CC}	- Power (+5V)
GND	- Ground
NC	- No Connect

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DESCRIPTION

The DS1230 256k Nonvolatile SRAMs are 262,144-bit, fully static, nonvolatile SRAMs organized as 32,768 words by 8 bits. Each NV SRAM has a self-contained lithium energy source and control circuitry which constantly monitors V_{CC} for an out-of-tolerance condition. When such a condition occurs, the lithium energy source is automatically switched on and write protection is unconditionally enabled to prevent data corruption. DIP-package DS1230 devices can be used in place of existing 32k x 8 static RAMs directly conforming to the popular bytewide 28-pin DIP standard. The DIP devices also match the pinout of 28256 EEPROMs, allowing direct substitution while enhancing performance. DS1230 devices in the Low Profile Module package are specifically designed for surface-mount applications. There is no limit on the number of write cycles that can be executed and no additional support circuitry is required for microprocessor interfacing.

READ MODE

The DS1230 devices execute a read cycle whenever $\overline{\text{WE}}$ (Write Enable) is inactive (high) and $\overline{\text{CE}}$ (Chip Enable) and $\overline{\text{OE}}$ (Output Enable) are active (low). The unique address specified by the 15 address inputs (A₀ - A₁₄) defines which of the 32,768 bytes of data is to be accessed. Valid data will be available to the eight data output drivers within t_{ACC} (Access Time) after the last address input signal is stable, providing that $\overline{\text{CE}}$ and $\overline{\text{OE}}$ (Output Enable) access times are also satisfied. If $\overline{\text{OE}}$ and $\overline{\text{CE}}$ access times are not satisfied, then data access must be measured from the later-occurring signal ($\overline{\text{CE}}$ or $\overline{\text{OE}}$) and the limiting parameter is either t_{CO} for $\overline{\text{CE}}$ or t_{OE} for $\overline{\text{OE}}$ rather than address access.

WRITE MODE

The DS1230 devices execute a write cycle whenever the \overline{WE} and \overline{CE} signals are active (low) after address inputs are stable. The later-occurring falling edge of \overline{CE} or \overline{WE} will determine the start of the write cycle. The write cycle is terminated by the earlier rising edge of \overline{CE} or \overline{WE} . All address inputs must be kept valid throughout the write cycle. \overline{WE} must return to the high state for a minimum recovery time (twr) before another cycle can be initiated. The \overline{OE} control signal should be kept inactive (high) during write cycles to avoid bus contention. However, if the output drivers are enabled (\overline{CE} and \overline{OE} active) then \overline{WE} will disable the outputs in topy from its falling edge.

DATA RETENTION MODE

The DS1230AB provides full functional capability for V_{CC} greater than 4.75 volts and write protects by 4.5 volts. The DS1230Y provides full functional capability for V_{CC} greater than 4.5 volts and write protects by 4.25 volts. Data is maintained in the absence of V_{CC} without any additional support circuitry. The nonvolatile static RAMs constantly monitor V_{CC} . Should the supply voltage decay, the NV SRAMs automatically write protect themselves, all inputs become "don't care," and all outputs become high-impedance. As V_{CC} falls below approximately 3.0 volts, a power switching circuit connects the lithium energy source to RAM to retain data. During power-up, when V_{CC} rises above approximately 3.0 volts the power switching circuit connects external V_{CC} to RAM and disconnects the lithium energy source. Normal RAM operation can resume after V_{CC} exceeds 4.75 volts for the DS1230AB and 4.5 volts for the DS1230Y.

FRESHNESS SEAL

Each DS1230 device is shipped from Dallas Semiconductor with its lithium energy source disconnected, guaranteeing full energy capacity. When V_{CC} is first applied at a level greater than 4.25 volts, the lithium energy source is enabled for battery back-up operation.

PACKAGES

The DS1230 devices are available in two packages: 28-pin DIP and 34-pin PowerCap Module (PCM). The 28-pin DIP integrates a lithium battery, an SRAM memory and a nonvolatile control function into a single package with a JEDEC-standard, 600-mil DIP pinout. The 34-pin PowerCap Module integrates SRAM memory and nonvolatile control along with contacts for connection to the lithium battery in the DS9034PC PowerCap. The PowerCap Module package design allows a DS1230 PCM device to be surface mounted without subjecting its lithium backup battery to destructive high-temperature reflow soldering. After a DS1230 PCM is reflow soldered, a DS9034PC PowerCap is snapped on top of the PCM to form a complete Nonvolatile SRAM module. The DS9034PC is keyed to prevent improper attachment. DS1230 PowerCap Modules and DS9034PC PowerCaps are ordered separately and shipped in separate containers. See the DS9034PC data sheet for further information.

ABSOLUTE MAXIMUM RATINGS*

Voltage on Any Pin Relative to Ground -0.3V to +6.0V

Operating Temperature

0°C to 70°C, -40°C to +85°C for IND parts

Storage Temperature

-40°C to +70°C, -40°C to +85°C for IND parts

Soldering Temperature

DIP Module +260°C for 10 seconds
Caution: Do Not Reflow (Wave or Hand Solder Only)
PowerCap Module See IPC/JEDEC J-STD-020

RECOMMENDED DC OPERATING CONDITIONS

(t_A: See Note 10)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
DS1230AB Power Supply Voltage	V_{CC}	4.75	5.0	5.25	V	
DS1230Y Power Supply Voltage	V_{CC}	4.5	5.0	5.5	V	
Logic 1	V_{IH}	2.2		V_{CC}	V	
Logic 0	$V_{\rm IL}$	0.0		0.8	V	

DC ELECTRICAL CHARACTERISTICS

(V_{CC} =5 $V \pm 5\%$ for DS1230AB)

 $(t_A: See Note 10) (V_{CC}=5V \pm 10\% for DS1230Y)$

	(-A		<i>)</i> (- CC			,
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Leakage Current	I_{IL}	-1.0		+1.0	μΑ	
I/O Leakage Current $\overline{CE} \ge V_{IH} \le V_{CC}$	I_{IO}	-1.0		+1.0	μΑ	
Output Current @ 2.4V	I_{OH}	-1.0			mA	
Output Current @ 0.4V	I_{OL}	2.0			mA	
Standby Current $\overline{\text{CE}} = 2.2 \text{V}$	I_{CCS1}		200	600	μΑ	
Standby Current $\overline{CE} = V_{CC} - 0.5V$	I_{CCS2}		50	150	μΑ	
Operating Current	I_{CCO1}			85	mA	
Write Protection Voltage (DS1230AB)	V_{TP}	4.50	4.62	4.75	V	
Write Protection Voltage (DS1230Y)	V_{TP}	4.25	4.37	4.5	V	

^{*} This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

CAPACITANCE $(t_A=25^{\circ}C)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Input Capacitance	C_{IN}		5	10	pF	
Input/Output Capacitance	$C_{I/O}$		5	10	pF	

AC ELECTRICAL CHARACTERISTICS

(V_{CC}=5V $\pm\,5\%$ for DS1230AB)

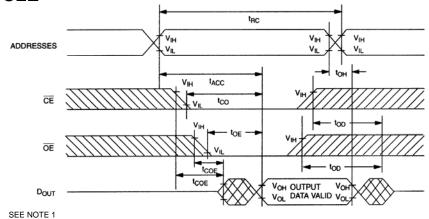
(t_A: See Note 10) (V_{CC} =5 $V \pm 10\%$ for DS1230Y)

OHARAGIER			0AB-70	DS123	0AB-85	DS123	0AB-100		12301)
PARAMETER	SYMBOL		30Y-70		30Y-85		30Y-100	UNITS	NOTES
		MIN	MAX	MIN	MAX	MIN	MAX		
Read Cycle Time	t _{RC}	70		85		100		ns	
Access Time	t _{ACC}		70		85		100	ns	
OE to Output Valid	t _{OE}		35		45		50	ns	
CE to Output Valid	t_{CO}		70		85		100	ns	
OE or CE to Output Active	t _{COE}	5		5		5		ns	5
Output High Z from Deselection	t _{OD}		25		30		35	ns	5
Output Hold from Address Change	t _{OH}	5		5		5		ns	
Write Cycle Time	t_{WC}	70		85		100		ns	
Write Pulse Width	t_{WP}	55		65		75		ns	3
Address Setup Time	t_{AW}	0		0		0		ns	
Write Recovery Time	t _{WR1}	5 15		5 15		5 15		ns	12 13
Output High Z from WE	t _{ODW}		25		30		35	ns	5
Output Active from WE	t _{OEW}	5		5		5		ns	5
Data Setup Time	$t_{ m DS}$	30		35		40		ns	4
Data Hold Time	t _{DH1} t _{DH2}	0 10		0 10		0 10		ns	12 13

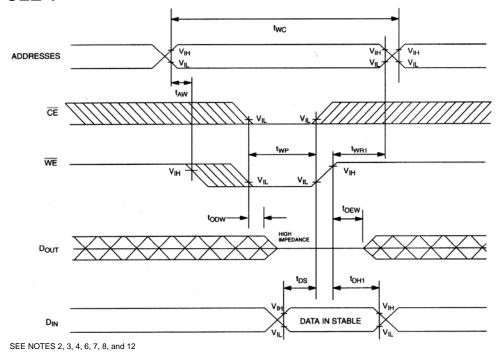
AC ELECTRICAL CHARACTERISTICS (cont'd)

PARAMETER	SYMBOL		0AB-120 30Y-120		0AB-150 30Y-150		30AB-200 30Y-200	UNITS	NOTES
		MIN	MAX	MIN	MAX	MIN	MAX		
Read Cycle Time	t_{RC}	120		150		200		ns	
Access Time	t _{ACC}		120		150		200	ns	
OE to Output Valid	t _{OE}		60		70		100	ns	
CE to Output Valid	t_{CO}		120		150		200	ns	
OE or CE to Output Active	t_{COE}	5		5		5		ns	5
Output High Z from Deselection	t _{OD}		35		35		35	ns	5
Output Hold from Address Change	t _{OH}	5		5		5		ns	
Write Cycle Time	t_{WC}	120		150		200		ns	
Write Pulse Width	t_{WP}	90		100		100		ns	3
Address Setup Time	t_{AW}	0		0		0		ns	
Write Recovery Time	t _{WR1}	5 15		5 15		5 15		ns	12 13
Output High Z from WE	t _{ODW}		35		35		35	ns	5
Output Active from WE	t _{OEW}	5		5		5		ns	5
Data Setup Time	$t_{ m DS}$	50		60		80		ns	4
Data Hold Time	t _{DH1} t _{DH2}	0 10		0 10		0 10		ns	12 13

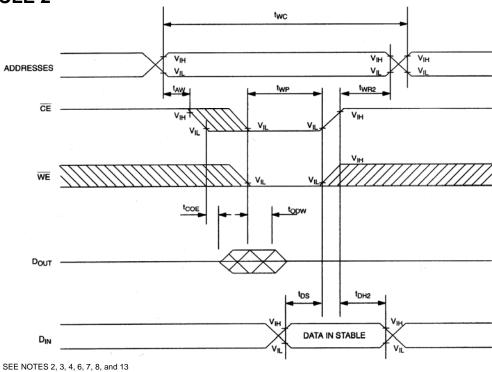
READ CYCLE



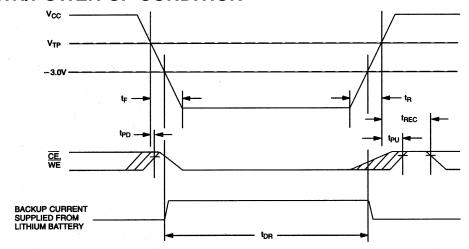
WRITE CYCLE 1



WRITE CYCLE 2



POWER-DOWN/POWER-UP CONDITION



SEE NOTE 11

POWER-DOWN/POWER-UP TIMING

(t_A: See Note 10)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
V_{CC} Fail Detect to \overline{CE} and \overline{WE} Inactive	t_{PD}			1.5	μs	11
V_{CC} slew from V_{TP} to $0V$	t_{F}	150			μs	
V _{CC} slew from 0V to V _{TP}	t_R	150			μs	
V_{CC} Valid to \overline{CE} and \overline{WE} Inactive	t_{PU}			2	ms	
V _{CC} Valid to End of Write Protection	t_{REC}			125	ms	

 $(t_A=25^{\circ}C)$

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Expected Data Retention Time	t_{DR}	10			years	9

WARNING:

Under no circumstance are negative undershoots, of any amplitude, allowed when device is in battery backup mode.

NOTES:

- 1. $\overline{\text{WE}}$ is high for a Read Cycle.
- 2. $\overline{OE} = V_{IH}$ or V_{IL} . If $\overline{OE} = V_{IH}$ during write cycle, the output buffers remain in a high-impedance state.
- 3. t_{WP} is specified as the logical AND of \overline{CE} and \overline{WE} . t_{WP} is measured from the latter of \overline{CE} or \overline{WE} going low to the earlier of \overline{CE} or \overline{WE} going high.
- 4. t_{DH} , t_{DS} are measured from the earlier of \overline{CE} or \overline{WE} going high.
- 5. These parameters are sampled with a 5 pF load and are not 100% tested.
- 6. If the $\overline{\text{CE}}$ low transition occurs simultaneously with or latter than the $\overline{\text{WE}}$ low transition, the output buffers remain in a high-impedance state during this period.
- 7. If the $\overline{\text{CE}}$ high transition occurs prior to or simultaneously with the $\overline{\text{WE}}$ high transition, the output buffers remain in high-impedance state during this period.
- 8. If $\overline{\text{WE}}$ is low or the $\overline{\text{WE}}$ low transition occurs prior to or simultaneously with the $\overline{\text{CE}}$ low transition, the output buffers remain in a high-impedance state during this period.
- 9. Each DS1230 has a built-in switch that disconnects the lithium source until the user first applies V_{CC} . The expected t_{DR} is defined as accumulative time in the absence of V_{CC} starting from the time power is first applied by the user. This parameter is assured by component selection, process control, and design. It is not measured directly during production testing.
- 10. All AC and DC electrical characteristics are valid over the full operating temperature range. For commercial products, this range is 0°C to 70°C. For industrial products (IND), this range is -40°C to +85°C.
- 11. In a power-down condition the voltage on any pin may not exceed the voltage on V_{CC}.
- 12. t_{WR1} and t_{DH1} are measured from \overline{WE} going high.
- 13. t_{WR2} and t_{DH2} are measured from \overline{CE} going high.
- 14. DS1230 modules are recognized by Underwriters Laboratory (U.L.®) under file E99151.

DC TEST CONDITIONS

Outputs Open Cycle = 200 ns for operating current All voltages are referenced to ground

AC TEST CONDITIONS

Output Load: 100 pF + 1TTL Gate
Input Pulse Levels: 0 - 3.0V
Timing Measurement Reference Levels

Input: 1.5V Output: 1.5V

Input pulse Rise and Fall Times: 5 ns

ORDERING INFORMATION

SI230AB-70	OKDEKING IN	ORMATION	G 1	1	
DS 1230AB-70+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 70ns	Part Number	Temperature Range	Supply Tolerance	Pin/Package	Speed Grade
DS1230ABP-70	DS1230AB-70	0°C to +70°C	5V ± 5%	28 / 740 EMOD	
DS1230ABP-70+	DS1230AB-70+	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	
DS1230AB-70IND	DS1230ABP-70	0°C to +70°C	$5V \pm 5\%$	34 / PowerCap*	70ns
DS1230AB-70IND+	DS1230ABP-70+	0°C to +70°C	5V ± 5%	34 / PowerCap*	70ns
DS1230ABP-70IND	DS1230AB-70IND	-40°C to +85°C	5V ± 5%	28 / 740 EMOD	70ns
DS1230ABP-70IND+	DS1230AB-70IND+	-40°C to +85°C	5V ± 5%	28 / 740 EMOD	70ns
DS1230AB-85	DS1230ABP-70IND	-40°C to +85°C	5V ± 5%	34 / PowerCap*	
DS1230AB-85+ 0°C to +70°C 5V±5% 28 / 740 EMOD 85ns DS1230AB-100 0°C to +70°C 5V±5% 28 / 740 EMOD 100ns DS1230AB-100+ 0°C to +70°C 5V±5% 28 / 740 EMOD 100ns DS1230AB-100 0°C to +70°C 5V±5% 34 / PowerCap* 100ns DS1230ABP-100 0°C to +70°C 5V±5% 34 / PowerCap* 100ns DS1230ABP-100+ 0°C to +70°C 5V±5% 34 / PowerCap* 100ns DS1230AB-120 0°C to +70°C 5V±5% 34 / PowerCap* 100ns DS1230AB-120 0°C to +70°C 5V±5% 28 / 740 EMOD 120ns DS1230AB-120+ 0°C to +70°C 5V±5% 28 / 740 EMOD 120ns DS1230AB-120IND -40°C to +85°C 5V±5% 28 / 740 EMOD 120ns DS1230AB-120IND -40°C to +85°C 5V±5% 28 / 740 EMOD 120ns DS1230AB-120IND+ 40°C to +85°C 5V±5% 28 / 740 EMOD 120ns DS1230AB-130 0°C to +70°C 5V±5% 28 / 740 EMOD 150ns DS1230AB-150+ 0°C to +70°C 5V±5% 28 / 740 EMOD 150ns DS1230AB-150+ 0°C to +70°C 5V±5% 28 / 740 EMOD 150ns DS1230AB-200+ 0°C to +70°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200+ 0°C to +70°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200HD -40°C to +85°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200IND -40°C to +85°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200IND -40°C to +85°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V±5% 28 / 740 EMOD 200ns DS1230Y-70+ 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230Y-70+ 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230Y-70HD -40°C to +85°C 5V±10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V±10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V±10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V±10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230Y-100H 0°C to +70°C 5V±10% 34 / PowerCap* 100ns DS1230Y-100H 0°C to +70°C 5V±10% 28 / 740 EMOD 120ns	DS1230ABP-70IND+	-40°C to +85°C	5V ± 5%		70ns
DS1230AB-100	DS1230AB-85	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	85ns
DS1230AB-100+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 100ns	DS1230AB-85+	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	85ns
DS1230ABP-100	DS1230AB-100	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	100ns
DS1230ABP-100+	DS1230AB-100+	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	100ns
DS1230AB-120	DS1230ABP-100	0°C to +70°C	$5V \pm 5\%$	34 / PowerCap*	100ns
DS1230AB-120H	DS1230ABP-100+	0°C to +70°C	$5V \pm 5\%$	34 / PowerCap*	
DS1230AB-120IND	DS1230AB-120		$5V \pm 5\%$	28 / 740 EMOD	120ns
DS1230AB-120IND+ -40°C to +85°C 5V ± 5% 28 / 740 EMOD 120ns DS1230AB-150 0°C to +70°C 5V ± 5% 28 / 740 EMOD 150ns DS1230AB-150+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 150ns DS1230AB-200 0°C to +70°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230Y-70 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD </td <td>DS1230AB-120+</td> <td>0°C to +70°C</td> <td>5V ± 5%</td> <td>28 / 740 EMOD</td> <td>120ns</td>	DS1230AB-120+	0°C to +70°C	5V ± 5%	28 / 740 EMOD	120ns
DS1230AB-150 0°C to +70°C 5V ± 5% 28 / 740 EMOD 150ns DS1230AB-150+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 150ns DS1230AB-200 0°C to +70°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230Y-70 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD <td>DS1230AB-120IND</td> <td>-40°C to +85°C</td> <td>$5V \pm 5\%$</td> <td>28 / 740 EMOD</td> <td>120ns</td>	DS1230AB-120IND	-40°C to +85°C	$5V \pm 5\%$	28 / 740 EMOD	120ns
DS1230AB-150+ 0°C to +70°C 5V±5% 28 / 740 EMOD 150ns DS1230AB-200 0°C to +70°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200H 0°C to +70°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200IND -40°C to +85°C 5V±5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V±5% 28 / 740 EMOD 200ns DS1230Y-70 0°C to +70°C 5V±10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V±10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230YP-70+ 0°C to +70°C 5V±10% 34 / PowerCap* 70ns DS1230YP-70H 0°C to +85°C 5V±10% 34 / PowerCap* 70ns DS1230YP-70IND -40°C to +85°C 5V±10% 28 / 740 EMOD 70ns DS1230YP-70INDH -40°C to +85°C 5V±10% 28 / 740 EMOD 70ns DS1230YP-70INDH -40°C to +85°C 5V±10% 34 / PowerCap* 70ns <td>DS1230AB-120IND+</td> <td>-40°C to +85°C</td> <td>$5V \pm 5\%$</td> <td>28 / 740 EMOD</td> <td>120ns</td>	DS1230AB-120IND+	-40°C to +85°C	$5V \pm 5\%$	28 / 740 EMOD	120ns
DS1230AB-200 0°C to +70°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200+ 0°C to +70°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230Y-70 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V ± 10% 34 / PowerCap*	DS1230AB-150	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	150ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DS1230AB-150+	0°C to +70°C	$5V \pm 5\%$		150ns
DS1230AB-200IND -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230AB-200IND+ -40°C to +85°C 5V ± 5% 28 / 740 EMOD 200ns DS1230Y-70 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230YP-70 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND+ -40°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-85+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-100 0°C to +70°C 5V ± 10% 28 / 740 EMOD	DS1230AB-200	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	200ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DS1230AB-200+	0°C to +70°C	$5V \pm 5\%$	28 / 740 EMOD	200ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DS1230AB-200IND	-40°C to +85°C	$5V \pm 5\%$	28 / 740 EMOD	200ns
DS1230Y-70+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 70ns DS1230YP-70 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70IND+ -40°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-85+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-100 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 34 / Po	DS1230AB-200IND+	-40°C to +85°C	$5V \pm 5\%$	28 / 740 EMOD	200ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		I .	$5V \pm 10\%$		
DS1230YP-70+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-85+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230Y-100 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230Y-120 0°C to +70°C 5V ± 10% 28 / 740 EMOD 120ns DS1230Y-120h 0°C to +70°C 5V ± 10% 28 / 740 EMOD<			$5V \pm 10\%$		
DS1230Y-70IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230YP-70IND -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-85+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-100 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230Y-100+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230YP-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230Y-120 0°C to +70°C 5V ± 10% 28 / 740 EMOD 120ns DS1230Y-120HD -40°C to +85°C 5V ± 10% 28 / 740 EMOD	DS1230YP-70	0°C to +70°C	$5V \pm 10\%$	*	70ns
DS1230Y-70IND+ -40°C to +85°C 5V ± 10% 28 / 740 EMOD 70ns DS1230YP-70IND -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230YP-70IND+ -40°C to +85°C 5V ± 10% 34 / PowerCap* 70ns DS1230Y-85 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-85+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 85ns DS1230Y-100 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230Y-100+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230Y-100+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 100ns DS1230Y-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230Y-100+ 0°C to +70°C 5V ± 10% 34 / PowerCap* 100ns DS1230Y-100+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 120ns DS1230Y-120 0°C to +70°C 5V ± 10% 28 / 740 EMOD 120ns DS1230Y-120HD -40°C to +85°C 5V ± 10% 28 / 740 EMOD	DS1230YP-70+		$5V \pm 10\%$	34 / PowerCap*	70ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		-40°C to +85°C	$5V \pm 10\%$	28 / 740 EMOD	70ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DS1230Y-70IND+		$5V \pm 10\%$	28 / 740 EMOD	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230YP-70IND	-40° C to $+85^{\circ}$ C	$5V \pm 10\%$	34 / PowerCap*	70ns
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		-40°C to +85°C	$5V \pm 10\%$		
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		I .	$5V \pm 10\%$		
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DS1230Y-85+		$5V \pm 10\%$	28 / 740 EMOD	85ns
$\begin{array}{cccccccccccccccccccccccccccccccccccc$			$5V \pm 10\%$	28 / 740 EMOD	100ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$					
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230YP-100	0° C to $+70^{\circ}$ C	$5V \pm 10\%$	34 / PowerCap*	100ns
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	DS1230YP-100+	0° C to $+70^{\circ}$ C	$5V \pm 10\%$	34 / PowerCap*	100ns
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230Y-120	0°C to +70°C		28 / 740 EMOD	120ns
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230Y-120+	0°C to +70°C	$5V \pm 10\%$	28 / 740 EMOD	120ns
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230Y-120IND	I .	5V ± 10%	28 / 740 EMOD	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230Y-120IND+		5V ± 10%	28 / 740 EMOD	120ns
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	DS1230Y-150		5V ± 10%	28 / 740 EMOD	150ns
DS1230Y-200+ 0°C to +70°C 5V ± 10% 28 / 740 EMOD 200ns DS1230Y-200IND -40°C to +85°C 5V ± 10% 28 / 740 EMOD 200ns	DS1230Y-150+	0° C to $+70^{\circ}$ C	5V ± 10%	28 / 740 EMOD	150ns
DS1230Y-200IND $-40^{\circ}\text{C to} +85^{\circ}\text{C}$ $5\text{V} \pm 10\%$ $28 / 740 \text{ EMOD}$ 200ns	DS1230Y-200	0°C to +70°C	5V ± 10%		200ns
	DS1230Y-200+		5V ± 10%		200ns
DS1230Y-200IND+ -40°C to +85°C 5V + 10% 28 / 740 EMOD 200ns	DS1230Y-200IND		5V ± 10%	28 / 740 EMOD	
+ Denotes lead-free/RoHS-compliant product.	DS1230Y-200IND+	-40°C to +85°C	$5V \pm 10\%$	28 / 740 EMOD	200ns

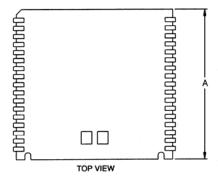
PACKAGE INFORMATION

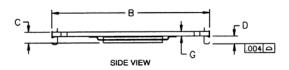
 $(For the \ latest\ package\ outline\ information,\ go\ to \underline{http://www.maxim-ic.com/DallasPackInfo}.)$

PACKAGE TYPE	DOCUMENT NO.
28 DIP	56-G0002-001

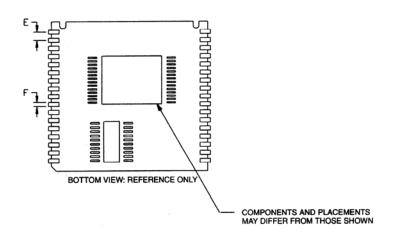
⁺ Denotes lead-free/RoHS-compliant product.
* DS9034PC or DS9034PCI (PowerCap) required. Must be ordered separately.

DS1230Y/AB NONVOLATILE SRAM, 34-PIN POWERCAP MODULE

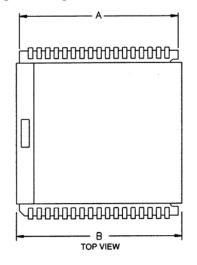




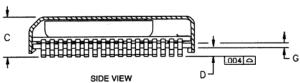
PKG	INCHES						
DIM	MIN	MAX					
Α	0.920	0.925	0.930				
В	0.980	0.985	0.990				
С	ı	-	0.080				
D	0.052	0.055	0.058				
Е	0.048	0.050	0.052				
F	0.015	0.020	0.025				
G	0.020	0.025	0.030				

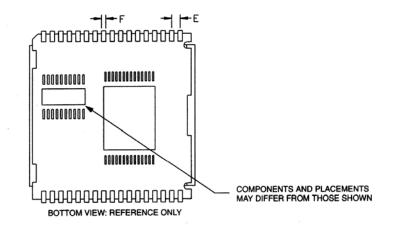


DS1230Y/AB NONVOLATILE SRAM, 34-PIN POWERCAP MODULE WITH POWERCAP



PKG	INCHES					
DIM	MIN	NOM	MAX			
Α	0.920	0.925	0.930			
В	0.955	0.960	0.965			
С	0.240	0.245	0.250			
D	0.052	0.055	0.058			
E	0.048	0.050	0.052			
F	0.015	0.020	0.025			
G	0.020	0.025	0.030			





ASSEMBLY AND USE

Reflow soldering

Dallas Semiconductor recommends that PowerCap Module bases experience one pass through solder reflow oriented label-side up (live-bug).

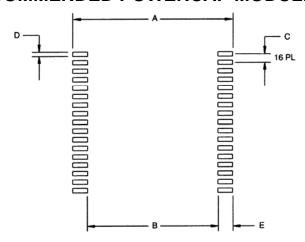
Hand soldering and touch-up

Do not touch soldering iron to leads for more than 3 seconds. To solder, apply flux to the pad, heat the lead frame pad and apply solder. To remove part, apply flux, heat pad until solder reflows, and use a solder wick.

LPM replacement in a socket

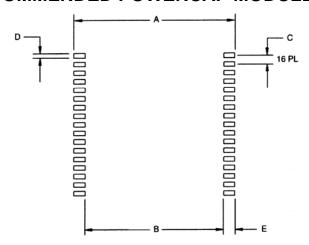
To replace a Low Profile Module in a 68-pin PLCC socket, attach a DS9034PC PowerCap to a module base then insert the complete module into the socket one row of leads at a time, pushing only on the corners of the cap. Never apply force to the center of the device. To remove from a socket, use a PLCC extraction tool and ensure that it does not hit or damage any of the module IC components. Do not use any other tool for extraction.

RECOMMENDED POWERCAP MODULE LAND PATTERN



PKG DIM	INCHES		
	MIN	NOM	MAX
Α	-	1.050	=
В		0.826	-
С	-	0.050	-
D	-	0.030	ı
E	-	0.112	-

RECOMMENDED POWERCAP MODULE SOLDER STENCIL



PKG DIM	INCHES		
	MIN	NOM	MAX
Α	-	1.050	-
В	-	0.890	-
С	-	0.050	-
D	-	0.030	-
Е	-	0.080	-

REVISION HISTORY

REVISION DATE	DESCRIPTION	PAGES CHANGED
121007	Added package information table.	0.10
121907	Removed the DIP module package drawing and dimension table.	9, 10